177%现代了

ELECTRONIC MATERIALS — OUR FUTURE

TN-2 E38 X

9462507

E38.7

SOCIETY FOR THE ADVANCEMENT OF MATERIAL AND PROCESS ENGINEERING



4th INTERNATIONAL SAMPE ELECTRONICS CONFERENCE

VOLUME 4

ELECTRONIC MATERIALS — OUR FUTURE

Albuquerque Hilton Hotel Albuquerque, New Mexico June 12 - 14, 1990



Edited by Ron E. Allred Robert J. Martinez Ken B. Wischmann



E9462507

10358220

Additional copies of this publication may be obtained from
Society for the Advancement of Material and Process Engineering

THEMSOMANG, LEWISCHATTE

SAMPE International Business Office
P.O. Box 2459
Covina, California 91722

Responsibility for the contents and security clearance of papers published herein rests solely upon the authors and not upon SAMPE or any of its members

CAMPAGAM



ISBN 0-938994-53-0

© 1990 by Society for the Advancement of Material and Process Engineering

4TH INTERNATIONAL SAMPE ELECTRONICS CONFERENCE

INTERNATIONAL OFFICERS

President

Executive Vice President

Senior Vice President

Vice President

Secretary

Ron S. Allred

Treasurer Immediate Past President

have a

Jerry Bauer

Brian A. Wilson

Bob J. Hunter

W. H. Face, Jr.

Roy E. Henrichsen

Patrick J. Phelan

G. B. Wadsworth

CHAPTER OFFICERS

(New Mexico Chapter)

Chairman

First Vice Chairman

Second Vice Chairman

Secretary

Treasurer

Student Chapter laison *

Sr. International Director

Jr. International Director

Timothy Towne Hewit

Nicholas J. Delollis

Howard W. Arris

A. P. Schlies

Douglass F. Wilson

Robert J. Martinez

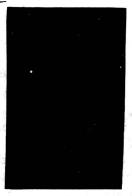
Ken Wischmann

cabanet Skilling The state of the state of a lixed the to we were

4TH INTERNATIONAL SAMPE ELECTRONICS CONFERENCE COMMITTEE



Robert J. Martinez Sandia National Labs General Chairman



Ken B. Wischmann Sandia National Labs Program Chairman



Ron E. Allred PDA Engineering Program Co-Chairman

John P. Tipton Finance Chairman General Electric (retired)

> Doug Wilson Co-Finance Chairman Rust Company

Mike D. Lucas Arrangements Chairman Sandia National Labs

Howard W. Arris Registration Chairman Sandia National Labs

Terry Scott Exhibits Chairman Smalley and Company David L. Zamora Hospitality Chairman Sandia National Labs

Tim Hewitt Audio-Visual Chairman Devore Aviation

A. P. 'Dolph' Schlies Public Relations/Secretary General Electric (retired)

H. L. 'Buddy' Anderson Publications Chairman Sandia National Labs

Katy Moore Student Chapter Liaison University of New Mexico

Debbie Beardon Student Chapter Liaison University of New Mexico

SESSIONS AND SESSION CHAIRMEN

SURFACE MOUNT TECHNOLOGY

Roald Horton, Westinghouse Electronics Systems Group DIELECTRIC MATERIALS

L. Lamarre, Hydro-Quebec

PACKAGING FOR SEVERE ENVIRONMENTS

Gerald Cessac, Sandia National Labs

PRINTED WIRING BOARD MATERIALS

Art Long, Westinghouse R & D Center

MICROWAVE APPLICATIONS, RADOMES

Alan Goldberg, Harry Diamond Labs

ADVANCED PLASTICS/POLYMERS

Ron Bauer, Shell Development Company

ELECTRONIC ADHESIVES

Maury Edwards, Hysol Corporation

SUPERCONDUCTOR MATERIALS

Toivo Kodas, University of New Mexico

PHOTONICS AND CONDUCTIVE POLYMERS I

Leonard Buckley, Naval Air Development Center

RIGID FLEX CIRCUITS

Adra Smith, Sandia National Labs

ADVANCED POLYMERS FOR ELECTRONICS

Robert Boshan, Lockheed Aeronautical Systems
DIELECTRIC MATERIALS

Robert Rossi, National Starch and Chemical Corporation SURFACE MOUNT TECHNOLOGY II

A. W. Noblett, Honeywell-Marine Systems

MANUFACTURING PROCESS CONTROLS

Larry Lichtenberg, Motorola Corporation

ELECTRONIC CERAMICS

Adam Wu, University of New Mexico

COATINGS AND ENCAPSULANTS

Gary Fugate, Texas Instruments

EMI SHIELDING

Steve Gertisen, Wilson Fiberfill

PREFACE

The New Mexico Chapter of the Society for the Advancement of Material and Process Engineering is honored to host the 4th International SAMPE Electronic Materials and Processes Conference in Albuquerque, New Mexico. The theme for our conference is "Electronic Materials -- Our Future". Technological breakthroughs in electronic devices have become increasingly materials dependent. Thus, if we are to keep pace in the highly competitive technology, then Electronic Materials are "Our Future". In keeping with our conference theme, we have assembled a program with some of the most know-ledgeable and technically respected people in the electronic materials field. Since SAMPE has dedicated itself to be a world leader in the electronic materials field, we feel this type of conference will once again prove that SAMPE is truly a society that will meet the needs of the entire materials family.

This conference will cover materials and processes for printed wiring boards, coatings and encapsulants, EMI shielding, electronic ceramics, surface mount technologies, and a very special session on the processing of superconductor materials. During prescribed times we will also offer exhibits from companies throughout the United States.

As you might expect, this type of conference would not exist without the help of many people, especially our dedicated conference committee. A special thanks to our new student chapter for all the help and volunteers they provided. A special thanks to Daun White for helping in setting up our exhibit area and also to the entire International Business Office staff. We would also like to thank our session chairmen, authors and exhibitors for a very successful and rewarding conference.

Robert J. Martinez General Chairman Ken B. Wischmann Program Chairman Ron E. Allred Program Co-Chairman

CONTENTS

	COPYRIGHT		iv		
	SPONSORING CHAPTER AND OFFICERS	6.7	v		
	ELECTRONICS CONFERENCE COMMITTE	E	vi		
	SESSIONS AND SESSION CHAIRMEN		vii		
	PREFACE		ix	· . · · · · · · · · · · · · · · · · · ·	
ADV. CAV	TABLE OF CONTENTS		xi		
	PAPERS AND AUTHORS		xii		
	INDICES		840		
	AUTHORS				
	COMPANY				
	SUBJECT				
	•				
	Account a pas w son				
STANDARD	S TO SOLED FOWER PENEED S				

MOLE DA LIKE TRAMPHEN WITH FLIM MINT THE CONTROL A CORE OF THE CONTROL AND A \$100.

TO PROPER OF THE SPEECE SERVICES OF POLICE OF POLICE OF PROPERTY OF PROPERTY OF PROPERTY OF THE PROPERTY OF TH

	Page
SOLDERLESS ALTERNATIVES TO SURFACE MOUNT COMPONENT ATTACHMENT	1
Robert A. Bourdelaise	
HIGH VOLTAGE TESTING OF COMPOSITES	11
Laurent Lamarre	
COMPOSITE MATERIALS FOR HIGH VOLTAGE OUTDOOR INSULATION	23
R. S. Gorur	4
DYNAMIC RESPONSE OF A COMPLEX ENCAPSULATED ELECTRONIC ASSEMBLY SUBJECTED TO A SEVERE SHOCK ENVIRONMENT	33
Steven N. Burchett	
SEVERE SHOCK AND VIBRATION ENVIRONMENTS FOR ELECTRONIC COMPONENTS	46
David R. Martinez	
RADIATION REQUIREMENTS FOR ELECTRONIC COMPONENTS IN NUCLEAR AND SPACE ENVIRONMENTS	61
P. S. Winokur	
DEVELOPMENT AND QUALIFICATION OF MATERIALS AND PROCESSES FOR RADIATION SHIELDING OF GALILEO SPACECRAFT ELECTRONIC COMPONENTS	67
F. Hribar, J. L. Bauer and T. P. O'Donnell	
SOLUBLE ORGANO-PALLADIUM COMPOUNDS IN LAMINATES AS SEED FOR ELECTROLESS PLATING	81
D. W. Wang, W. J. Summa, C. M. Boyko and E. O. Fey	9
APPLICATIONS OF HIGH THERMAL CONDUCTIVITY GRAPHITE COPPER IN STANDARD ELECTRONIC MODULES AND PRINTED WIRING BOARD POWER PLANES	94
John J. Glatz, Juan F. Leon and Fred L. Beavers	
APPLICATIONS OF ADVANCED COMPOSITES IN A 3/4 AIR TRANSPORTABLE RACK	108
John Glatz, J. Leon, W. Dittmer and R. Morgan	
RECENT TRENDS IN PWB SUBSTRATESTHE 1970'S REVISITED	122
Douglas J. Sober	
HIGH PERFORMANCE RETAINED IN FIRE IGNITION RESISTANT CYANATE ESTER RESIN SYSTEMS	132
Georgia A. Monnerat and Peter B. Dulcamara	
SILICON CARBIDE WHISKER REINFORCED ALUMINUM WITH LOW THERMAL EXPANSION	147
Jeng-Maw Chiou and D. D. L. Chung	
POLYBUTADINE AND MODIFIED POLYBUTADIENE THERMOSETS AS LOW DIELECTRIC POLYMER MATRIX AND COATINGS FOR RADOMES AND ANTENNAS	158
Horace R. Sessions, Jr., John M. Labriola and Ronald E. Drake	
EXPERIMENTAL OBSERVATIONS OF THE PLASTIC MEMORY PHENOMENON OCCURRING IN POLYETHER ETHER KETONE/GRAPHITE AND POLYBUTYLENE TERAPHTHALATE GRAPHITE COUPONS	167

Dave R. Rourk

,	Page
ANTENNA SURVIVABILITY: CONCERNS ON ENVIRONMENTAL STRESS SCREENING FOR STRIPLINE SLOTTED ARRAY ANTENNAS	179
Steven D. Willis, Mahesh K. Shah, Allen W. Hullenaar and James F. Landers	v
EVALUATION OF MICROWAVE SUBSTRATE MATERIALS FOR ELECTRICAL AND MECHANICAL PROPERTIES	194
Peter A. Bellus and Thomas P. Fontana	
DCPD NOVOLAC BASED THERMOSET RESINS FOR STRUCTURAL COMPOSITES	199
P. M. Puckett and C. A. Swartz	
IMIDE CONTAINING MULTIPHASE BLOCK POLYMERS AND THEIR USES IN THE MICROELECTRONICS INDUSTRY	214
James L. Hedrick, Jeff W. Labadie and W. Volkensen	
COPOLY (IMIDE-AMIDES) CONTAINING HEXAFLUOROISOPROPYLIDENE	223
David J. Irvin, Patrick E. Cassidy and Mitch L. Cameron	
PT RESIN AN EASILY PROCESSIBLE, LOW DIELECTRIC TOUGHENED THERMOSET FOR 600°F SERVICE TEMPERATURE	229
Sajal Das and B. T. DeBona	
ALUMINUM NITRIDE AND DIAMOND PARTICLE FILLED POLYMIDESILOXANE AS DIELECTRICS WITH LOW THERMAL EXPANSION AND INCREASED THERMAL CONDUCTIVITY	236
Lin Li and D. D. L. Chung	
LOW T POXY ADHESIVES FOR THERMAL MANAGEMENT	241
g Kevin K. T. Chung, Eldon Avery, Andy Boyle, Garrett Dreier, William Koehn, Guido Govaert and Dirk Theunissen	
CONDUCTIVE EPOXIES FOR ATTACHMENT OF SURFACE MOUNT DEVICES	255
H. Yoshigahara, Y. Sagami, S. Nose and A. Burkhart	
INVESTIGATIONS OF A MODEL DIE ATTACH ADHESIVE	267
R. C. Benson, T. E. Phillips, N. deHaas and M. Bonneau	
DEVELOPMENT OF A THERMAL TRANSFER ADHESIVE FOR SPACE ELECTRONICS	282
Ralph D. Hermansen, Robert B. Mitsuhashi, James C. Cammarata and Matthew T. Mika	
SILVER FILLED POLYIMIDESILOXANE DIE ATTACH MATERIAL	291
My N. Nguyen and Julie H. Wood	
PULSED LASER PROCESSING OF HIGH TEMPERATURE SUPERCONDUCTING THIN FILMS	302
R. E. Muenchausen, R. C. Dye, R. C. Estler, S. Foltyn, A. R. Garcia, K. M. Hubbard, N. S. Nogar, X. D. Wu, A. Carim, A. Mukherjee and S. R. J. Brueck	
OVERVIEW OF CURRENT BULK AND THICK FILM HIGH TEMPERATURE SUPER-CONDUCTOR PROCESSING STRATEGIES	316
Kevin C. Ott and Rod K. Ouinn	

•	Page
AEROSOL-ASSISTED CHEMICAL VAPOR DEPOSITION OF Y-Ba-Cu-O FILMS	327
Kevin C. Ott, Kenneth V. Salazar and Toivo T. Kodas	
AEROSOL PROCESSING OF SUPERCONDUCTING CERAMICS	331
Toivo T. Kodas	
ELECTRICALLY CONDUCTIVE LANGMUIR-BLODGETT FILMS PRODUCED BY ION IRRADIATION	334
K. F. Schoch, Jr., W-F. A. Su and J. Bartko	
LANGMUIR-BLODGETT FABRICATION OF NOVEL MOLECULAR ASSEMBLIES OF ELECTRICALLY CONDUCTIVE POLYPYRROLES	346
R. B. Rosner, J. H. Cheung and M. F. Rubner	17
ELECTROCHEMICAL AND SPECTROSCOPIC PROPERTIES OF POLY-3-METHYLTHIOPHENE	357
S. N. Hoier and Su-Moon Park	33,
OXIDATIVE POLYMERIZATION OF ANILINE: CHARACTERIZATION OF NEW POLYANILINE PRODUCTS	367
Sandra Preto-Clement and Randy E. Cameron	x
STRATEGY FOR THE DEVELOPMENT OF MACROMOLECULAR NONLINEAR OPTICAL MATERIALS	377
Braja K. Mandal, Jan-Chan Huang, Jayant Kumar and Sukant Tripathy	
NEW DEVELOPMENTS IN "SEMIORGANIC" NONLINEAR OPTICAL CRYSTALS	388
L. F. Warren	300
NEW FLEXIBLE CIRCUIT MATERIAL EVALUATION	398
David J. Fossey	370
EVALUATIONS OF NEW POLYIMIDE FILMS FOR FLEXIBLE CIRCUIT APPLICATIONS AT EG&G MOUND APPLIED TECHNOLOGIES	407
Melvin K. Williams, Margaret Huelskamp, Jeanne Brandon, Mark Fisher, Adra Smith and Thomas Wittberg	
THERMAL EXPANSION OF BETA-EUCRYPTITE FILLED BISMALEIMIDE AND GLASS/BISMALEIMIDE COMPOSITES	413
Ronald E. Allred, William D. Drotning and William E. Warren	
ELECTRICALLY CONDUCTING POWDER FILLED POLYIMIDESILOXANE	428
Lin Li and D. D. L. Chung	,20
STRESS PHENOMENA IN MULTILAYER STRUCTURES OF ALUMINUM AND SPUN-ON POLYIMIDESILOXANE FILMS	442
S. P. Sun, S. P. Murarka and C. J. Lee	
MICROSCOPIC INVESTIGATIONS OF THE AS-DEPOSITED AND ANNEALED POLYIMIDESILOXANE FILMS	453
S. P. Murarka, S. P. Sun and C. J. Lee	
PHOTOSENSITIVE POLYIMIDESILOXANES: A COMPARATIVE STUDY OF COMPOSITIONS AND PERFORMANCES	462

	Page
A NEW POLYIMIDE FOR A MULTI-LEVEL PLANAR DIELECTRIC LAYER	468
Takao Miwa, Takayoshi Ikeda and Shunichi Numata	
ACETYLENE-TERMINATED POLYIMIDE OLIGOMERS AS THE INTERLAYER DIELECTRIC FOR MULTILEVEL INTERCONNECTS MECHANICAL AND ADHESIVE EVALUATIONS	481
R. D. Rossi, P. D. Machiesky, J. S. Fenelli and J. M. McMahon	
NEW LOW DIELECTRIC CONSTANT POLYIMIDE BLOCK AND RANDOM COPOLYMERS	495
Jeff W. Labadie and James L. Hedrick	
ACETYLENE FUNCTIONAL POLYIMIDE OLIGOMERS AS LOW DIELECTRIC POLYMERS FOR MULTILEVEL STRUCTURES	507
J. E. Connors, L. F. Fuller, K. H. Hesler, C. Publisi, J. McMahon, A. Winster and R. D. Rossi	
THERMAL CHARACTERISTICS OF SPIN-ON POLYIMIDESILOXANE FILMS FOR APPLICATION AS INTERLEVEL DIELECTRIC	519
S. P. Sun, S. P. Murarka and C. J. Lee	Ţ
ELECTRICAL CHARACTERISTICS OF POLYIMIDESILOXANE FILMS	530
S. P. Sun, S. P. Murarka and C. J. Lee	
THERMALLY STABLE, LOW DIELECTRIC POLYQUINOLINES FOR AEROSPACE AND ELECTRONICS APPLICATIONS	544
Neil H. Hendricks, Matthew L. Marrocco, Diane M. Stoakley and Anne K. St. Clair	
ASSEMBLY PROCESSES FOR HYBRID WAFER-SCALE INTERCONNECT SUBSTRATES AND SCREEN-TEST RELIABILITY EVALUATIONS	556
Dale W. Swanson and Laura A. Hughes	
TIN WHISKERS: MECHANISM OF GROWTH AND PREVENTION	569
Kathleen M. Cunningham and Michael P. Donahue	
LOW TCR Pd-Ag ALLOY THICK FILM RESISTORS	576
Charles Y. Kuo and Tom O. Martin	
MONITORING ATTRIBUTE DATA FOR LOW-DEFECT PRODUCTS AND PROCESSES	589
J. Ronald Lawson and John Hathaway	
VARIABILITY REDUCTION THE KEY TO CONTINUOUS IMPROVEMENT	600
Alex Miseirvitch	
PROCESS ENGINEERING AND FLOW SOLDER: AN EXPANDED ROLE	607
Paul Johnson	
ELIMINATING THE NEED FOR 100% SOLDER JOINT INSPECTION	616
Victor G. Mosca	
CORRELATION OF CHEMICAL MICROSTRUCTURE WITH SOLDERABILITY OF PCBs	628
Larry Lichtenberg, James L. Marshall, Denis E. Miller and Jennifer Sees	
PROCESS CONTROLS RELATING TO SOLDER COOLING RATES	643

		Page
	OPTICALLY ADDRESSED INTEGRATED SPATIAL LIGHT MODULATOR	656
	Jeff A. Bullington and Joseph T. Evans	
	R-F TRIODE MAGNETRON SPUTTER DEPOSITION OF FERROELECTRIC (9/65/35) LEAD LANTANUM ZIRCONIUM TITANATE (PLZT) ON SAPPHIRE	666
	S. Krishnakumar, S. C. Esener, C. Cozzolino, C. Fan, V. H. Ozguz and S. H. Lee	
	ELECTRICAL AND OPTICAL MEASUREMENTS ON THIN FILM PLZT	673
	S. Mancha, M. Ivey, R. Carter and G. LaVigne	
	HUMIDITY-RELATED CHANGES IN THE ELECTRICAL PROPERTIES OF PZT THIN FILMS	686
	Mark Ivey, Sylvia Mancha and Robert Carter	
	REDUCTION/OXIDATION EFFECTS IN PLZT CERAMICS Gene H. Haertling	699
	ELECTRO-OPTIC PROPERTIES OF (Pb,La) (Zr,Ti)O3, BaTiO3 (Sb,Ba)Nb2O6 AND Ba2NaNb5O15 THIN FILMS BY A CONFOCAL SCANNING DIFFERENTIAL POLARIZATION MICROSCOPE Feiling Wang, Ching-Bo Juang, Carlos Bustamante and A. Y. Wu	712
	DEPOSITION OF (Pb,La) (Zr,Ti)O ₃ , BaTiO ₃ , (Sr,Ba) Nb ₂ O ₆ Ba ₂ NaNb ₅ O ₁₅ , KTiOPO ₄ , AND BETA-BaB ₂ O ₄ THIN FILMS	722
	A. Y. Wu	
	EVALUATION OF ANTISTATIC POLYETHYLENE PACKAGING MATERIALS Huey-Ling Ding	734
,	DETERMINATION OF OPTIMUM CURE TIMES ON ENCAPSULATES UTILIZING THERMAL ANALYSIS TECHNIQUES	745
	Charles R. Woods, Jr. and Gary W. Fugate	
	RAPID IMPINGEMENT MOLDING (RIM) ENCAPSULATION OF A FUZE POWER SUPPLY	753
	Mel Morganstein and Allan B. Goldberg	
	CORROSION CONCERNS IN EMI SHIELDING SYSTEMS	765
	George A. Lee, David J. Greenwood and Eric J. Carlson	
	ELECTROMAGNETIC INTERFERENCE BY CARBON FIBER REINFORCED POLYETHER SULFONE	777
	Lin Li and D. D. L. Chung	
	STATUS REPORT ON SHIELDING EFFECTIVENESS MEASUREMENTS: RELEASE OF ASTM STANDARD D4935-89	786
	John W. Adams	
	STAINLESS STEEL COMPOSITES FOR ESD/EMI APPLICATIONS	· 796
	Susan Ward, Anne Bolvari and Brian Gorry	
	EMI-RFI SHIELDING OF ELECTRONICS WITH CONDUCTIVE PLASTICS	806
	Mal Murthy	

EMI	GASKETING MATERIALS: A PERFORMANCE COMPARISON		819
	Robert C. Mulhall, Robert J. Teichmann and Monica A. Gi	11oon	
THE	EVOLVING STATIC CONTROL OPTIONS FOR THERMOPLASTICS		829
	Michael I Marasch		

SOLDERLESS ALTERNATIVES TO SURFACE MOUNT COMPONENT ATTACHMENT

Robert A. Bourdelaise

Westinghouse Electronic Systems Group Baltimore, Maryland 21203

ABSTRACT

Solder has been the primary method of component attachment since the early days of radio. This tradition carries with it an overhead that becomes increasingly expensive as the degree of miniaturization increases. Solderless interconnect methods, however, are often overlooked or unfairly discounted as unreliable. Surprisingly, solderless connections can be mechanically superior and environmentally more robust than their soldered peers. This paper reviews various solderless interconnect techniques for surface mount applications and discusses their relative merits.

1. INTRODUCTION

Although convenient and readily available, soldering technology can quickly become very inconvenient when applied to dimensionally large or fine-pitch surface-mount packages or when contractually obligated to meet military electronics assembly quality requirements. Specifically, solder has these shortcomings: high temperature exposure of the component during solder reflow (a potential reliability impact), corrosive solvent exposure (fluxes, deoxidizers, and cleansers), sophisticated process control, labor/capital-intensive assembly, high degree of inspection (connection quality often subjective), and susceptibility to mechanical fatigue. Alternately, a solderless approach offers: inherent compliance to thermally induced dimensional changes, connection quality that is quantitative, and far less complicated and labor intensive assembly processes.

This paper will address the following categories of solderless interconnection: conductive epoxies, memory metals, elastomers, wire bonding, and button-board techniques. Table 1 illustrates the broad range of choices and their domestic sources.

Table 1. The Variety of Solderless Component Attachment Techniques Offers Many Choices

Categories	Techniques	Typical Use	Manufacturer
Epoxies	Silver Filled	Chip devices	Abelstik
	Gold Filled	Hybrids	Abelstik
4	Unidirectional	Leadless Carriers	Uniax
Memory metals	Heat to Activate	Connector/Socket	Beta Phase
	Cool to Activate	Socket	Raychem
Elastomers	Metal Plated Silicon Stack	Key Pads	PCK Elastomerics
	Elastomer w/ Aggregate Fill	Test Socket	ATT
	Elastomer w/ Spring Contact	Test Socket	Rogers Corp.
Wire Bonding	Wire Bond Package to PWB	High Density	Westinghouse
Button Board	Compliant Spring in Carrier	Area Array Package	e Cinch Connector

1.1 Conductive Epoxies

This approach is perhaps the most commonly used substitute for solder. Pin and socket (connectors) are of course more common but are not a surface-mount technique. Use of epoxies eliminates many of the process-related difficulties of solder, but has little impact on the design of the product, as shown in the implementation of a surface-mount chip component of Figure 1. Conductive epoxies are most often used within a hermetic package to attach integrated circuits or discrete chip capacitors/resistors. They are typically found as a silver filled epoxy but can also be obtained in a gold filled variety. A new class of epoxies having anisotropic properties that permit conduction in only one axis are also available and can be used to attach a fine pitch, high density, multicontact component.

1.1.1 Advantages

Peaceful Coexistence. Conductive epoxies are often used on substrates requiring a mixture
of wire bonded and surface mount chip components.

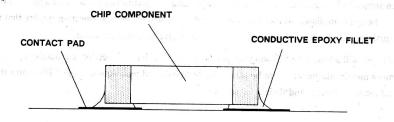


Figure 1. Chip components are similarly attached with epoxy as with solder but footprint pad dimensions can be tighter.

- Smaller Component Footprints. Since epoxy does not "wet" the way solder does, footprints
 of chip components may be less generous in pad area because the fillet spread can be more
 tightly controlled.
- Lower Curing Temperatures. Curing of most epoxies usually occurs at temperatures much lower than solder reflows (150°C compared to 280°C). In the case of unidirectional epoxies, attachment requires only a momentary pressure on the component while ultraviolet (UV) or low temperature cured.
- Better Fatigue Characteristics. By definition, epoxies are compliant, more fatigue resistant, and repairable with less likelihood of damage to adjacent components.

1.1.2 Disadvantages

- Environmental Susceptibility. A major disadvantage, particularly in military applications of the silver-filled variety, is its poor resistance to environment. Humid conditions under electrical bias will cause silver to grow dendrites, as do unprotected copper, nickel, and tin. One way around this is the use of gold-filled epoxies, but with more expense.
- Time Dependent Life. Although typically considered as the opportunity cost, shelf life of
 epoxies are limited and often require refrigerated storage at -40°C. Unless substantially automated, application, particularly for small components, can be labor intensive.

1.2 Memory Metals

Memory metals are a class of alloys (such as Nitinol) that change their crystalline phase when heated (or, for some, cooled) to a specific temperature. This shift in internal structure can induce tremendous forces and result in a mechanical advantage. Although the examples shown in Figures 2 and 3 are not directly surface mount related, they are illustrated here as examples of varied application that could be applied to surface mount technology.

Figure 2 uses the memory metal that changes state when cooled to liquid nitrogen temperatures. The socket member pressed into the printed wiring board (PWB) is made from beryllium copper, acts as an opening spring and is surrounded by a memory metal collar. When cooled, the memory metal enlarges and allows the Be/Cu socket to open against the memory metal collar, thus releasing the grip on the component's lead. Alternately, Figure 3 uses the memory metal in a backplane connector application that opens against a trough-shaped closing spring when heated to 85°C by a heating element integral to the flex circuit.

1.2.1 Advantages

Gas Tight Connection. The primary advantage of memory metals are their ability to form
gas-tight contacts without the use of solder. This is possible because the closing spring can
exert up to twice the normal force on the contact than a conventional friction fit contact. Because temperature is used, tooless component attachment and release can be effected at low
cost.

1.2.2 Disadvantages

High PWB Real Estate Overhead. Unfortunately, current memory metal implementations
are application specific and not directly applicable to high density component attachment. As